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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/735,414	12/12/2003	Wolfgang Dettmann	2002 P 13806 US	2142
48154	7590 01/24/2006		EXAMINER	
SLATER & MATSIL LLP 17950 PRESTON ROAD			AKANBI, ISIAKA O	
SUITE 1000			ART UNIT PAPER NUMBER	
DALLAS, T	X 75252		2877	
			DATE MAILED: 01/24/2006	6

Please find below and/or attached an Office communication concerning this application or proceeding.

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	Application No.	Applicant(s)				
Office Action Commence	10/735,414	DETTMANN ET AL.				
Office Action Summary	Examiner	Art Unit				
•	Isiaka O. Akanbi	2877				
The MAILING DATE of this communication app Period for Reply	ears on the cover sheet with the c	orrespondence address				
A SHORTENED STATUTORY PERIOD FOR REPLY WHICHEVER IS LONGER, FROM THE MAILING DA - Extensions of time may be available under the provisions of 37 CFR 1.13 after SIX (6) MONTHS from the mailing date of this communication. - If NO period for reply is specified above, the maximum statutory period w - Failure to reply within the set or extended period for reply will, by statute, Any reply received by the Office later than three months after the mailing earned patent term adjustment. See 37 CFR 1.704(b).	ATE OF THIS COMMUNICATION 36(a). In no event, however, may a reply be tim rill apply and will expire SIX (6) MONTHS from cause the application to become ABANDONE	J. lely filed the mailing date of this communication (35 U.S.C. § 133).				
Status						
1) Responsive to communication(s) filed on 12 De	ecember 2003					
•	action is non-final.					
3) Since this application is in condition for allowar		secution as to the merits i	9			
closed in accordance with the practice under E	· ·		•			
·	A parto Quayro, 1000 O.D. 11, 40	0.0.210.				
Disposition of Claims						
4)⊠ Claim(s) <u>1-21</u> is/are pending in the application.						
4a) Of the above claim(s) is/are withdraw	vn from consideration.					
5) Claim(s) is/are allowed.						
6) Claim(s) 1, 2, 4, 7-18 is/are rejected.						
7)⊠ Claim(s) <u>3,5,6 and 19-21</u> is/are objected to.						
8) Claim(s) are subject to restriction and/or	r election requirement.					
Application Papers						
9) The specification is objected to by the Examine	r.					
10)⊠ The drawing(s) filed on 22 December 2003 is/a	re: a)⊠ accepted or b)⊡ object	ed to by the Examiner.				
Applicant may not request that any objection to the		•				
Replacement drawing sheet(s) including the correct			(d).			
11) The oath or declaration is objected to by the Ex	· · · · · · · · · · · · · · · · · · ·		` '			
Priority under 35 U.S.C. § 119						
 12) Acknowledgment is made of a claim for foreign a) All b) Some * c) None of: 1. Certified copies of the priority documents 2. Certified copies of the priority documents 3. Copies of the certified copies of the priority application from the International Bureau * See the attached detailed Office action for a list 	s have been received. s have been received in Applicati ity documents have been receive i (PCT Rule 17.2(a)).	on No ed in this National Stage				
Attachment(s) 1) Notice of References Cited (PTO-892) 2) Notice of Draftsperson's Patent Drawing Review (PTO-948) 3) Information Disclosure Statement(s) (PTO-1449 or PTO/SB/08) Paper No(s)/Mail Date 10 May 2004.	4) Interview Summary Paper No(s)/Mail Da 5) Notice of Informal P 6) Other:					

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DETAILED ACTION

Information Disclosure Statement

The information disclosure statement file 10 May 2004 has been entered and reference considered by the examiner.

Drawings

The examiner approves the drawings filed 12 December 2003.

Claim Rejections - 35 USC § 102

The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

(e) the invention was described in (1) an application for patent, published under section 122(b), by another filed in the United States before the invention by the applicant for patent or (2) a patent granted on an application for patent by another filed in the United States before the invention by the applicant for patent, except that an international application filed under the treaty defined in section 351(a) shall have the effects for purposes of this subsection of an application filed in the United States only if the international application designated the United States and was published under Article 21(2) of such treaty in the English language.

Claims 1, 2, 4, 7, 13-14 and 18 are rejected under 35 U.S.C. 102(e) as being anticipated by Danko (6,879,391 B1).

As regard to claims 1, 7 and 13, Danko discloses a method for inspection of periodic structures on a lithography mask using a microscope with adjustable illumination and an operating element used for movement of a mechanical stage wherein the lithography mask is attached to the mechanical stage in order to record images of the lithography mask at a computer-controlled location on the lithography mask, wherein a position, a size and a pitch specification of the mask are stored comprising of the following:

calibrating a first image of each array structure for selected locations on the lithography mask (fig. 1), calculating Fourier coefficients at a reference point of an array/diffraction grating (63), calculating a residual image (63) from a difference between an original image of the array structure and a Fourier expansion and forming a threshold value for the calculation of an image indicating an error (col. 4, line 35-50)(col. 6, line 22-col. 7, line 1-67).

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As to claims 2 and 18, Danko discloses wherein the calibrating is carried out by determining a mask rotation and determining a magnification (fig. 1)(col. 6, line 57-col. 7, line 1-55).

As to claim 4, Danko discloses wherein a frequency filter is used to reduce curling in the residual image (col. 2, line 21-32).

As to claim 14, Danko discloses repairing the lithography mask based upon results of the inspecting (fig. 1)(25).

Claim Rejections - 35 USC § 103

The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

Claims 8, 9, 10, 11,12 and 15-17 are rejected under 35 U.S.C. 103(a) as being unpatentable over Danko (6,879,391 B1) in view of the admitted prior art of applicant.

As to claims 8-10, Danko discloses the claimed invention, as applied to claim 7 above, except for is silent regarding wherein the lithography mask comprising a chromium mask, a half-tone mask or an interference mask, however the applicant discloses (col. 0054, line 1-3) that this is a well known. Therefore it would have been obvious to one having ordinary skill in the art at the time of invention to incorporate the teachings of Danko in conjunction with applicant indication of feature to provide a lithography mask that may be a chromium mask, a half-tone mask or an interference mask to meet the terms of the claims for the purpose of inspection and repairing. (see In Ex parte McGaughey, 6 USPQ2d 1334, 1337 (Bd. Pat. App. & Int.1988).

As to claims 11-12 and 15-17, Danko discloses the claimed invention, as applied to claim 7 and 14 above, except for is silent regarding wherein the repairing is carried out by means of ion etching or by use of an atom microscope for microprocessing of the lithography mask, however the applicant discloses (col. 0056, line 1-3) that this is a well known. Therefore it would have been obvious to one having ordinary skill in the art at the time of invention to incorporate the teachings of Danko in conjunction with applicant indication of feature to carried out by means of ion etching or by use of an atom microscope for microprocessing of the

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lithography mask to meet the terms of the claims for the purpose of inspecting and repairing lithography mask. Further, it would have been obvious to one having ordinary skill in the art at the time of invention to effect the semiconductor substrate comprising of forming a portion of an array of memory cells for the purpose of inspecting and repairing lithography mask. (see In Ex parte McGaughey, 6 USPQ2d 1334, 1337 (Bd. Pat. App. & Int.1988).

Allowable Subject Matter

Claims 3, 5-6, 19, 20 and 21 are objected to as being dependent upon a rejected base claim, but would be allowable if rewritten in independent form including all of the limitations of the base claim and any intervening claims.

As to claim 3, the prior art of record, taken alone or in combination, fails to disclose or render obvious wherein a rotation angle and a magnification factor are chosen such that a magnitude of the associated Fourier coefficient is a maximum.

As to claims 5 and 20, the prior art of record, taken alone or in combination, fails to disclose or render obvious determining a mean value of an error in a line width by forming an average value over all the measurement points and rejecting the lithography mask if the error in the line width is greater than the predetermined threshold value, further the prior art of record, taken alone or in combination, fails to disclose or render obvious converting the Fourier coefficients to a line width value by means of back-transformation and a predetermined intensity threshold value. Claim 6 and is allowable by virtue of its dependency on claim 5.

As to claim 21, the prior art of record, taken alone or in combination, fails to disclose or render obvious measuring the width of the image lines and the image lines separations by use of Fourier analysis.

Additional Prior Art

The prior art made of record and not relied upon is considered pertinent to applicant's disclosure. The references listed in the attached form PTO-892 teach of other prior art a method for inspection of periodic structures on a lithography mask using a microscope that may anticipate or obviate the claims of the applicant's invention.

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Conclusion

Fax/Telephone Information

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Isiaka Akanbi whose telephone number is (571) 272-8658. The examiner can normally be reached on 8:00 a.m. - 4:30 p.m.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Gregory J. Toatley Jr. can be reached on (571) 272-2800 ext. 77. The fax phone number for the organization where this application or proceeding is assigned is 703-872-9306.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

Isiaka Akanbi January 19, 2006

Supervision Payrit Examiner